Working model of microstructural evolution by bio-inspired processing

Modeling and simulation methods explore the physics behind a phenomenon and are often accompanied by powerful mathematics. These methods provide us with the ability to know the subject and inspire us to create useful engineering artifacts. A phenomenon of particular interest is the processing and properties of natural materials [1, 2]. By knowing this subject, we hope to be inspired by nature to create next-generation lightweight, high-strength and high-toughness engineering materials.

Natural materials, which have risen from billions of years of evolution, have developed unique characteristics. The fabrication of natural materials is very efficient and sustainable through a bottom-up self-assembly at ambient temperature and pressure. Among all the bio-inspiring processing methods to emulate the design and assembly principles learned from nature, freeze casting is a promising approach to form various bio-inspired structural materials with excellent microstructural control.

Freeze casting belongs to a broad field of freezing colloids, a phenomenon often observed and encountered in nature or in technology applications. Sea ice, freezing soils (frost heave) and the making of frozen dessert and ice cream are some of the widely known examples of freezing colloids. Freeze casting exploits the solidification (freezing) behavior of a solvent to form controllably porous ceramics, metals or polymers. By freezing a colloidal suspension, ice crystals nucleate on one side of the slurry and grow along with the external and controllable temperature gradient. The ice crystals redistribute the suspended particles as they grow within the slurry, effectively templating the desirable porous microstructure.

A study by Chuin-Shan Chen et al. [1] presents probably the first working phase-field model of a freezing colloidal suspension. As it is not computationally feasible to explicitly trace the motion of each colloidal particle by molecular dynamics or coarse-grained particle simulation, the modeling and simulation of the interactions of colloidal particles with a moving solidification interface are simplified in this work. Under the assumption that colloidal particles can be represented by a continuous concentration field, the interfacial condition of mass conservation, the Gibbs-Thomson condition, and particle segregation can be naturally included in the model.

A major difficulty in modeling a sharp interface is the stability of the associated partial differential equations. To this end, a free energy is constructed, and a diffusive phase-field model is derived. The finite element method

Figure 1. Modeling and simulation of the laminar and dendritical microstructure by the freeze-casting process. From left to right: laminar and dendritical microstructure, ice crystals redistribute the suspended particles as they grow within the slurry and the phase-field simulation.
A new approach to create silicon-germanium heterojunction nanowires

A single-phase semiconductor material, e.g., silicon and germanium, has intrinsic physical properties. When two semiconductor materials are joined to form “heterojunction” structures, special properties appear and can be used for applications in electronic, optoelectronic, and thermoelectric devices. To achieve ideal device performance, the heterojunction interface must be free of defects and possess compositional abruptness. Owing to recent advances in nanomaterial fabrication, defect-free heterojunction structures can be realized in nanowires. A nanowire is a one-dimensional structure with a diameter of less than 100 nanometers. When two sets of atoms with different periodicities are commensurately connected in a nanowire’s axial direction, the free surface of the nanowire sidewalls allows for atom displacement near the interface. The strain energy, which may cause interfacial defects, is reduced.

The method most routinely used for semiconductor nanowire growth includes a vapor-liquid-solid (VLS) mechanism. In this mechanism, semiconductor gas precursors are decomposed by liquid-phase catalysts, followed by precipitation of solid semiconductors at the liquid/solid interface. The nanoscale cross-sectional area of the liquid/